

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L9	42544	power adj (device or semiconductor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 21:04
L11	1980	10 and drift\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 21:04
L12	1101	11 and lateral\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 21:06
L13	958	12 and (remov\$6 or etch\$6 or recess\$6 or trench or groove)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 21:07
L14	928	13 and (contact or terminal or electr\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 21:08
L15	576	14 and (@ad<="20000921" or @rlad<="20000921")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 21:11

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	84	lateral adj power adj (semiconductor or device)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 20:43
L2	58	1 and (@ad<="20000921" or @rlad<="20000921")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 20:43
L5	44	4 and drift\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 20:45